NPN/NPN resistor-equipped transistors;

 $R1 = 10 k\Omega$ , R2 = 10 kΩ

Rev. 6 — 29 November 2011

**Product data sheet** 

## 1. Product profile

## 1.1 General description

NPN/NPN Resistor-Equipped Transistors (RET) in Surface-Mounted Device (SMD) plastic packages.

### Table 1. Product overview

Type number	Package		NPN/PNP		Package
	NXP	JEITA	complement	complement	configuration
PEMH11	SOT666	-	PEMD3	PEMB11	ultra small and flat lead
PUMH11	SOT363	SC-88	PUMD3	PUMB11	very small

## 1.2 Features and benefits

- 100 mA output current capability
- Built-in bias resistors
- Simplifies circuit design
- Reduces component count
- Reduces pick and place costs
- AEC-Q101 qualified

## 1.3 Applications

- Low current peripheral driver
- Control of IC inputs
- Replaces general-purpose transistors in digital applications

## 1.4 Quick reference data

### Table 2. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per transis	stor					
V <sub>CEO</sub>	collector-emitter voltage	open base	-	-	50	V
lo	output current		-	-	100	mA
R1	bias resistor 1 (input)		7	10	13	kΩ
R2/R1	bias resistor ratio		0.8	1	1.2	



2 3 sym063

## NPN/NPN resistor-equipped transistors; R1 = 10 k $\Omega$ , R2 = 10 k $\Omega$

# 2. Pinning information

Table 3.	Pinning		
Pin	Description	Simplified outline	Graphic symbol
1	GND (emitter) TR1		
2	input (base) TR1	6 5 4	
3	output (collector) TR2		
4	GND (emitter) TR2		
5	input (base) TR2		
6	output (collector) TR1	001aab555	

# 3. Ordering information

Table 4.         Ordering information					
Type number	Package				
	Name	Description	Version		
PEMH11	-	plastic surface-mounted package; 6 leads	SOT666		
PUMH11	SC-88	plastic surface-mounted package; 6 leads	SOT363		

# 4. Marking

Table 5. Marking codes	
Type number	Marking code <sup>[1]</sup>
PEMH11	H1
PUMH11	H*1

[1] \* = placeholder for manufacturing site code.

## NPN/NPN resistor-equipped transistors; R1 = 10 k $\Omega$ , R2 = 10 k $\Omega$

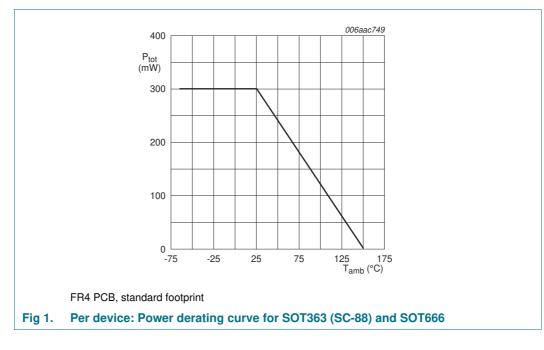
# 5. Limiting values

Symbol	Parameter	Conditions	Min	Max	Unit
Per transis	stor				
V <sub>CBO</sub>	collector-base voltage	open emitter	-	50	V
V <sub>CEO</sub>	collector-emitter voltage	open base	-	50	V
V <sub>EBO</sub>	emitter-base voltage	open collector	-	10	V
VI	input voltage				
	positive		-	+40	V
	negative		-	-10	V
lo	output current		-	100	mA
I <sub>CM</sub>	peak collector current		-	100	mA
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$	[1]		
	PEMH11 (SOT666)		[2] _	200	mW
	PUMH11 (SOT363)		-	200	mW
Per device	)				
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$	[1]		
	PEMH11 (SOT666)		[2] _	300	mW
	PUMH11 (SOT363)		-	300	mW
Tj	junction temperature		-	150	°C
T <sub>amb</sub>	ambient temperature		-65	+150	°C
T <sub>stg</sub>	storage temperature		-65	+150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

[2] Reflow soldering is the only recommended soldering method.

NPN/NPN resistor-equipped transistors; R1 = 10 k $\Omega$ , R2 = 10 k $\Omega$ 



# 6. Thermal characteristics

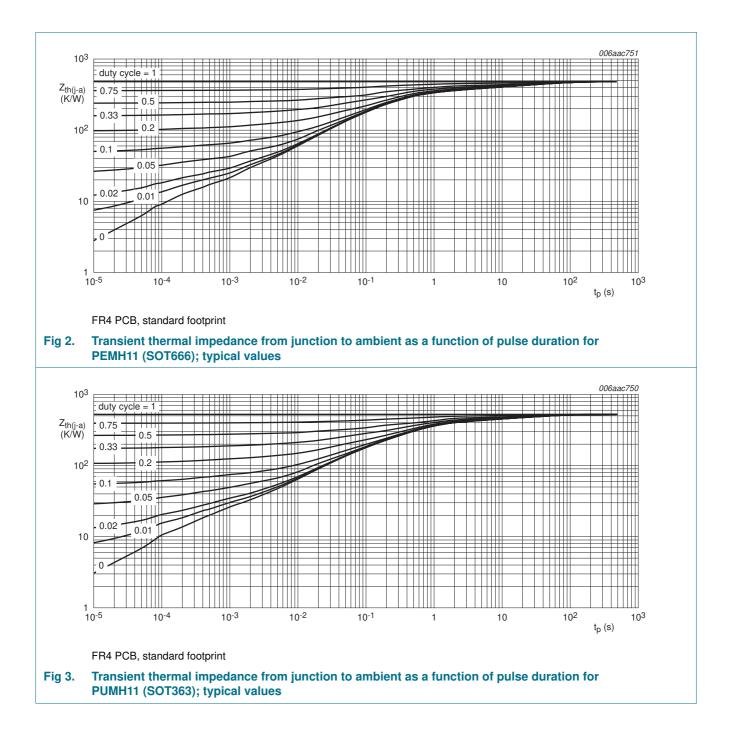
Table 7.	Thermal characteristic	S				
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per trans	istor					
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air	<u>[1]</u>			
	PEMH11 (SOT666)		[2] _	-	625	K/W
	PUMH11 (SOT363)		-	-	625	K/W
Per devic	e					
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air	<u>[1]</u>			
	PEMH11 (SOT666)		[2] _	-	417	K/W
	PUMH11 (SOT363)		-	-	417	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Reflow soldering is the only recommended soldering method.

# PEMH11; PUMH11

NPN/NPN resistor-equipped transistors; R1 = 10 k $\Omega$ , R2 = 10 k $\Omega$ 



## NPN/NPN resistor-equipped transistors; R1 = 10 k $\Omega$ , R2 = 10 k $\Omega$

# 7. Characteristics

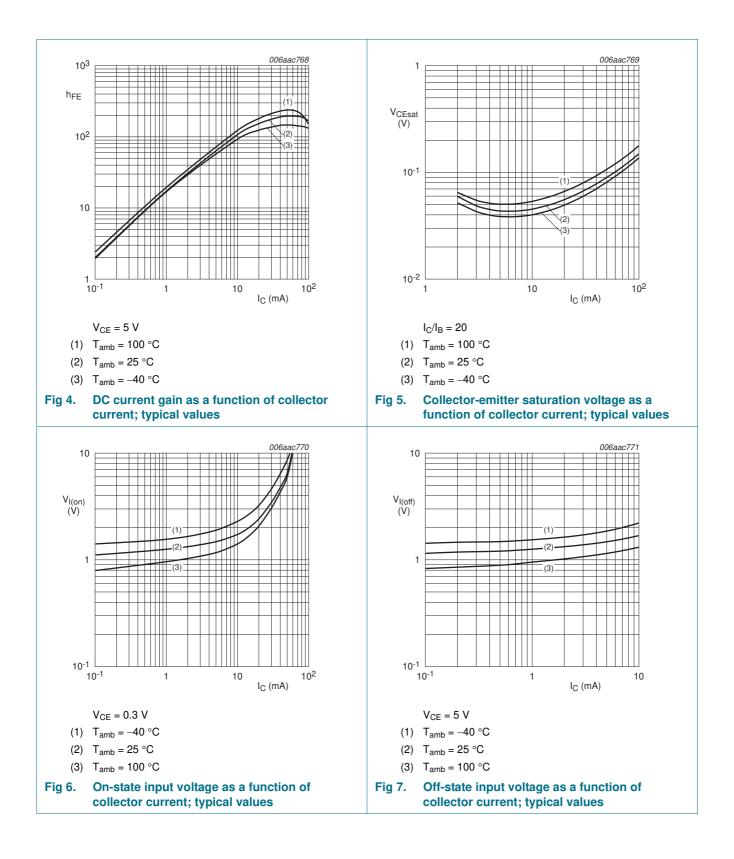
Symbol	Parameter	Conditions	Mi	n Typ	Мах	Unit
Per trans	istor					
I <sub>CBO</sub>	collector-base cut-off current	$V_{CB}=50~V;~I_{E}=0~A$	-	-	100	nA
I <sub>CEO</sub>	collector-emitter	$V_{CE} = 30 \text{ V}; \text{ I}_{B} = 0 \text{ A}$	-	-	1	μA
	cut-off current		-	-	5	μ <b>A</b>
I <sub>EBO</sub>	emitter-base cut-off current	$V_{EB}=5 \ V; \ I_C=0 \ A$	-	-	400	μA
h <sub>FE</sub>	DC current gain	$V_{CE} = 5 \text{ V}; I_C = 5 \text{ mA}$	30	-	-	
V <sub>CEsat</sub>	collector-emitter saturation voltage	$I_{C} = 10 \text{ mA}; I_{B} = 0.5 \text{ mA}$	-	-	150	mV
V <sub>I(off)</sub>	off-state input voltage	$V_{CE}=5~V;~I_C=100~\mu A$	-	1.1	0.8	V
V <sub>I(on)</sub>	on-state input voltage	$V_{CE}=0.3 \text{ V}; \text{ I}_{C}=10 \text{ mA}$	2.5	5 1.8	-	V
R1	bias resistor 1 (input)		7	10	13	kΩ
R2/R1	bias resistor ratio		0.8	3 1	1.2	
C <sub>c</sub>	collector capacitance	$\label{eq:VCB} \begin{split} V_{CB} &= 10 \text{ V}; \text{ I}_{E} = \text{i}_{e} = 0 \text{ A}; \\ \text{f} &= 1 \text{ MHz} \end{split}$	-	-	2.5	pF
f <sub>T</sub>	transition frequency	V <sub>CB</sub> = 5 V; I <sub>C</sub> = 10 mA; f = 100 MHz	<u>[1]</u> -	230	-	MHz

[1] Characteristics of built-in transistor.

PEMH11\_PUMH11
Product data sheet

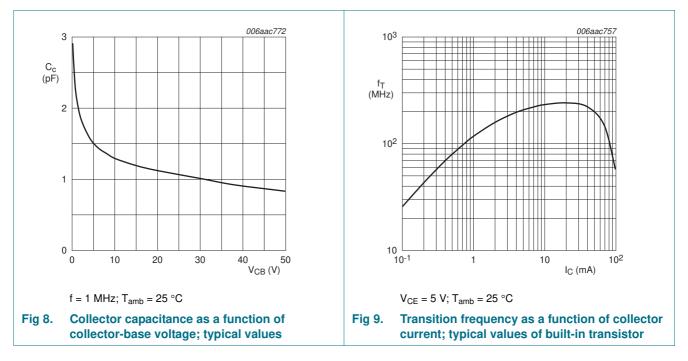
# PEMH11; PUMH11

### NPN/NPN resistor-equipped transistors; R1 = 10 k $\Omega$ , R2 = 10 k $\Omega$



# PEMH11; PUMH11

NPN/NPN resistor-equipped transistors; R1 = 10 k $\Omega$ , R2 = 10 k $\Omega$ 

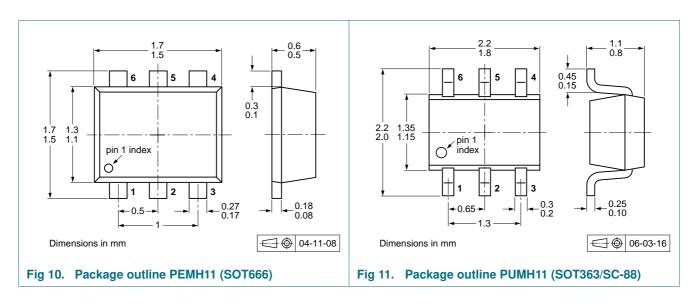


#### **Test information** 8.

## 8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

#### **Package outline** 9.



PEMH11 PUMH11

### NPN/NPN resistor-equipped transistors; R1 = 10 k $\Omega$ , R2 = 10 k $\Omega$

# **10. Packing information**

### Table 9. Packing methods

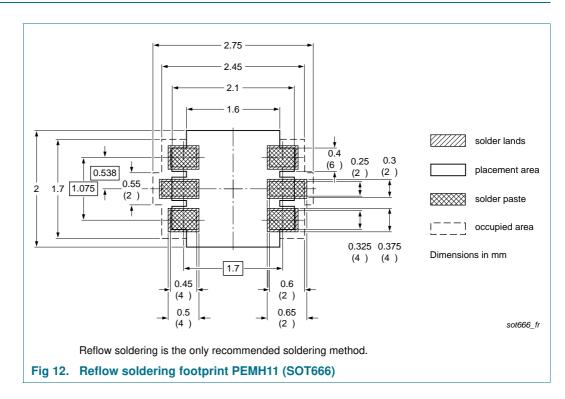
The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number Package		Description		Packing quantity			
				3000	4000	8000	10000
PEMH11	SOT666	2 mm pitch, 8 mm tape and reel		-	-	-315	-
		4 mm pitch, 8 mm tape and reel		-	-115	-	-
PUMH11 SOT363		4 mm pitch, 8 mm tape and reel; T1	[2]	-115	-	-	-135
		4 mm pitch, 8 mm tape and reel; T2	[3]	-125	-	-	-165

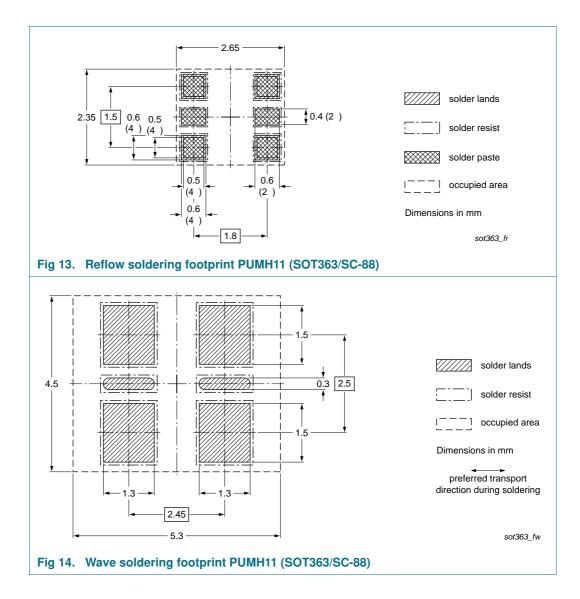
[1] For further information and the availability of packing methods, see <u>Section 14</u>.

- [2] T1: normal taping
- [3] T2: reverse taping

# 11. Soldering



### NPN/NPN resistor-equipped transistors; R1 = 10 k $\Omega$ , R2 = 10 k $\Omega$



PEMH11\_PUMH11
Product data sheet

NPN/NPN resistor-equipped transistors; R1 = 10 k $\Omega$ , R2 = 10 k $\Omega$ 

# 12. Revision history

Table 10. Revision history							
Document ID	Release date	Data sheet status	Change notice	Supersedes			
PEMH11_PUMH11 v.6	20111129	Product data sheet	-	PEMH11_PUMH11 v.5			
Modifications:	<ul> <li>The format of this document has been redesigned to comply with the new identity guidelines of NXP Semiconductors.</li> </ul>						
	<ul> <li>Legal texts have been adapted to the new company name where appropriate.</li> </ul>						
	<u>Section 1 "Product profile"</u> : updated						
	<u>Section 4 "Marking"</u> : updated						
	Table 7 "Thermal characteristics": updated according to the latest measurements						
	<ul> <li><u>Table 8 "Characteristics</u>": I<sub>CEO</sub> updated according to the latest measurements, V<sub>i(on)</sub> and V<sub>i(off)</sub> changed respectively to V<sub>I(on)</sub> and V<sub>I(off)</sub>, f<sub>T</sub> added</li> </ul>						
	• Figure 1 to 9: added						
	Section 8 "Test information": added						
	<ul> <li>Figure 10 and 11: replaced by minimized package outline drawings</li> </ul>						
	Section 10 "Packing information": added						
	Section 11 "Soldering": added						
	<ul> <li>Section 13 "</li> </ul>	Legal information": updated	d				
PEMH11_PUMH11 v.5	20031020	Product data sheet	-	PUMH11 v.4 PEMH11 v.1			
PUMH11 v.4	19990413	Product specification	-	-			
PEMH11 v.1	20011022	Preliminary specification	-	-			

# **13. Legal information**

## 13.1 Data sheet status

Document status[1][2]	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <a href="http://www.nxp.com">http://www.nxp.com</a>.

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### NPN/NPN resistor-equipped transistors; R1 = 10 k $\Omega$ , R2 = 10 k $\Omega$

**Quick reference data** — The Quick reference data is an extract of the product data given in the Limiting values and Characteristics sections of this document, and as such is not complete, exhaustive or legally binding.

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# PEMH11; PUMH11

NPN/NPN resistor-equipped transistors; R1 = 10 k $\Omega$ , R2 = 10 k $\Omega$ 

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